

## One Chip AM/FM Radio with Audio Power Amplifier

### Description

The integrated circuit TDA1083 includes, with exception of the FM front end, a complete AM-/FM-radio-circuit with audio power amplifier. An internal Z-diode

stabilizes the supply voltage at  $V_S \approx 13$  V, which allows with the aid of a resistor and a rectifier, the circuit to be driven by a higher external supply voltage.

### Features

- Large supply voltage range  $V_S = 3$  to  $12$  V
- High AM-Sensitivity
- Limiting threshold voltage  $V_i = 50$   $\mu$ V
- Audio output power  $P_0 = 0.7$  W

- AFC-connection for VHF-tuner
- AM-FM switching without high frequency voltages

### Applications

- AM-/FM- and audio-amplifier

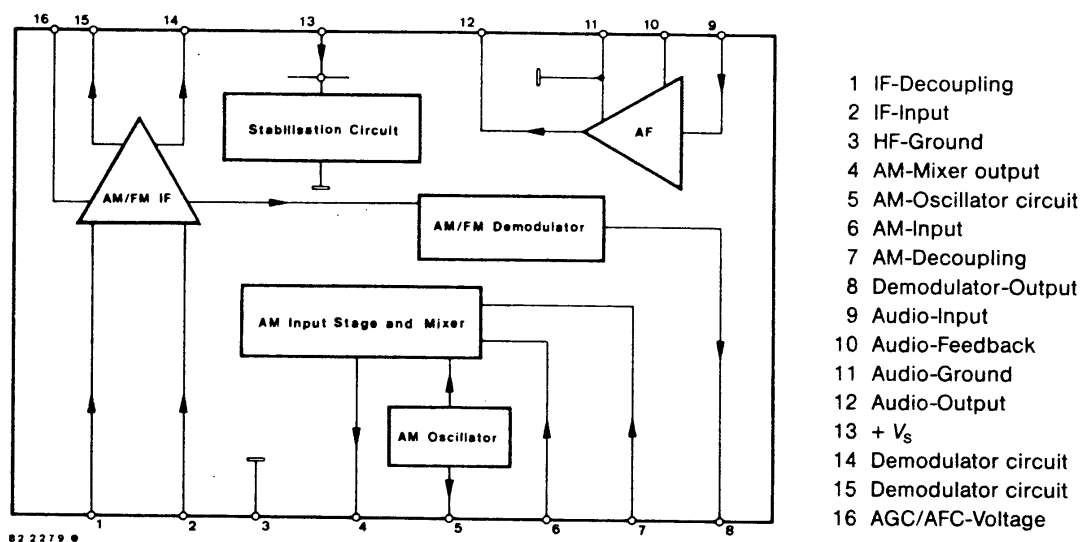


Figure 1. Block diagram and pin connections

### Absolute Maximum Ratings

Reference points Pin 3 and 11, unless otherwise specified

Parameters	Symbol	Value	Unit
Supply voltage range Pin 13	$V_S$	3 to 12	V
Supply current when using the integrated stabilization circuit, $V_S = 12.5$ to $14.3$ V Pin 13	$I_S$	50	mA
Power dissipation $T_{amb} = 65^\circ\text{C}$	$P_{tot}$	600	mW
Junction temperature	$T_j$	125	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-25 to +125	$^\circ\text{C}$

### Thermal Resistance

Parameters	Symbol	Maximum	Unit
Junction ambient	$R_{thJA}$	100	K/W

## Electrical Characteristics

$V_S = 9\text{ V}$ , reference points Pin 3 and 11,  $T_{\text{amb}} = 25^\circ\text{C}$ , unless otherwise specified

Parameters	Test Conditions / Pin	Symbol	Min	Typ	Max	Unit
<b>AF amplifier</b>						
AF voltage amplification	$f = 1\text{ kHz}$	$G_v$		40		dB
Input impedance		$R_i$		150		$k\Omega$
Output power	Figures 4 and 5 $V_S = 5.5\text{ V}$ , $R_L = 8\ \Omega$ , $k = 10\%$	$P_o$	300			mW
<b>AM-IF amplifier</b> , $f_i = 1\text{ MHz}$ , $f_{IF} = 455\text{ kHz}$ , $f_{\text{mod}} = 1\text{ kHz}$ , $m = 0.3$						
DC voltages at AM mode without signal	$V_S = 3\text{ V}$ Pin 10	$V_{10}$		1.2		V
	Pin 12	$V_{12}$	1.0		1.4	V
	Pin 13	$V_{13}$	3.0	3.0	3.0	V
	Pin 16	$V_{16}$	1.25		2.0	V
	$I_S = 42\text{ mA}$ Pin 10 ( $V_S = 12.5\text{ to }14.3\text{ V}$ )	$V_{10}$		1.2		V
	Pin 12	$V_{12}$	5.9		7.2	V
	Pin 13	$V_{13}$	12.5	13.3	14.3	V
	Pin 16	$V_{16}$	1.5		2.0	V
	Regulation range	$V_{oAF}/V_{oAF} = -10\text{ dB}$				
	Pin 6	$\Delta V_i$		70		dB
AF voltage at demodulator output	Pin 8	$V_{oAF}$		100		mV
<b>FM-IF amplifier</b> , $f_{IF} = 10.7\text{ MHz}$ , $\Delta f = \pm 22.5\text{ kHz}$ , $f_{\text{mod}} = 1\text{ kHz}$						
DC voltages at FM mode without signal	$V_S = 3\text{ V}$ Pin 10	$V_{10}$		1.2		V
	Pin 12	$V_{12}$	1.0		1.4	V
	Pin 13	$V_{13}$	3.0	3.0	3.0	V
	Pin 16	$V_{16}$	1.8		2.8	V
	$I_S = 42\text{ mA}$ Pin 10 ( $V_S = 12.5\text{ to }14.3\text{ V}$ )	$V_{10}$		1.2		V
	Pin 12	$V_{12}$	5.9		7.2	V
	Pin 13	$V_{13}$	12.5	13.3	14.3	V
	Pin 16	$V_{16}$	2.0		3.1	V
	Limiting threshold ( $-3\text{ dB}$ )	Pin 2	$V_i$	50		$\mu\text{V}$
	AF voltage at demodulator output	Pin 8	$V_{oAF}$	100		mV

Different dc voltages are developed at Pin 16 due to gain spread of AM-IF-amplifier. To determine the value of parallel resistance  $R_8$ , at the output of the demodulator Pin 8 for  $V_S = 9$  V, AM mode without signal, dc voltage should be selected at Pin 16.

Table 1. Available in following voltage groups:

$V_{16}$	1.4 to 1.7 V	1.7 to 1.9 V	1.9 to 2.1 V
$R_8$	$\infty$	47 k $\Omega$	33 k $\Omega$
Group	1	2	3

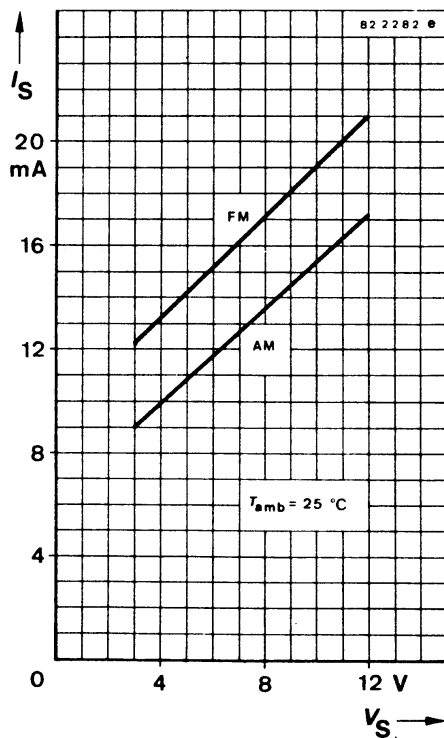


Figure 2.

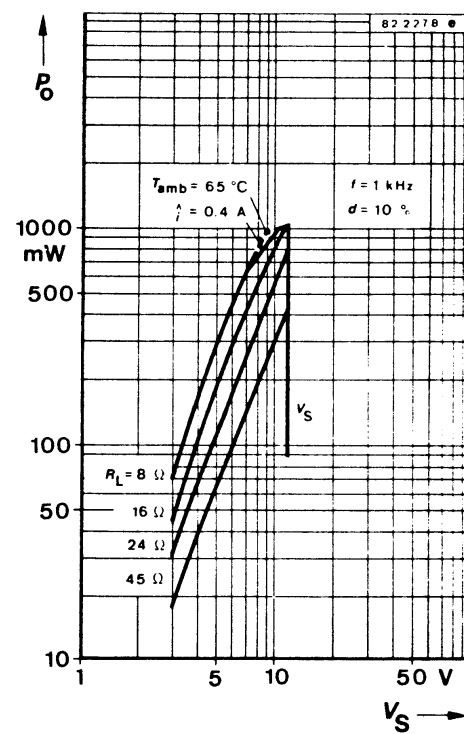


Figure 3.

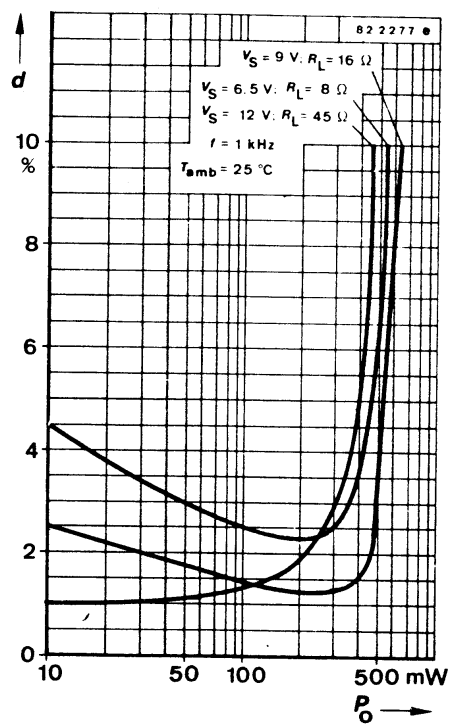


Figure 4.

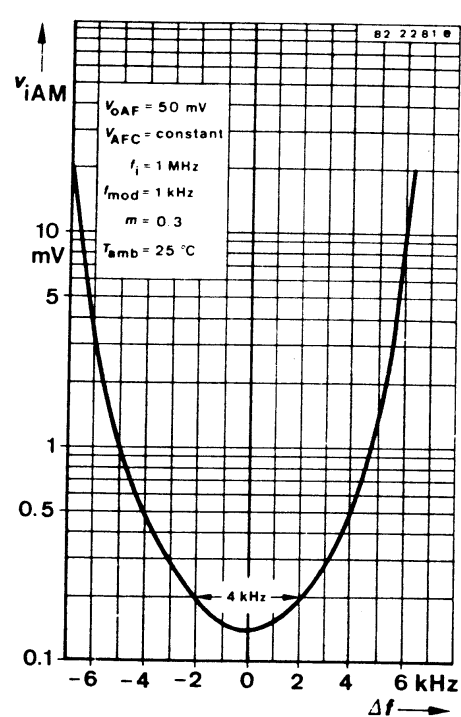


Figure 5.

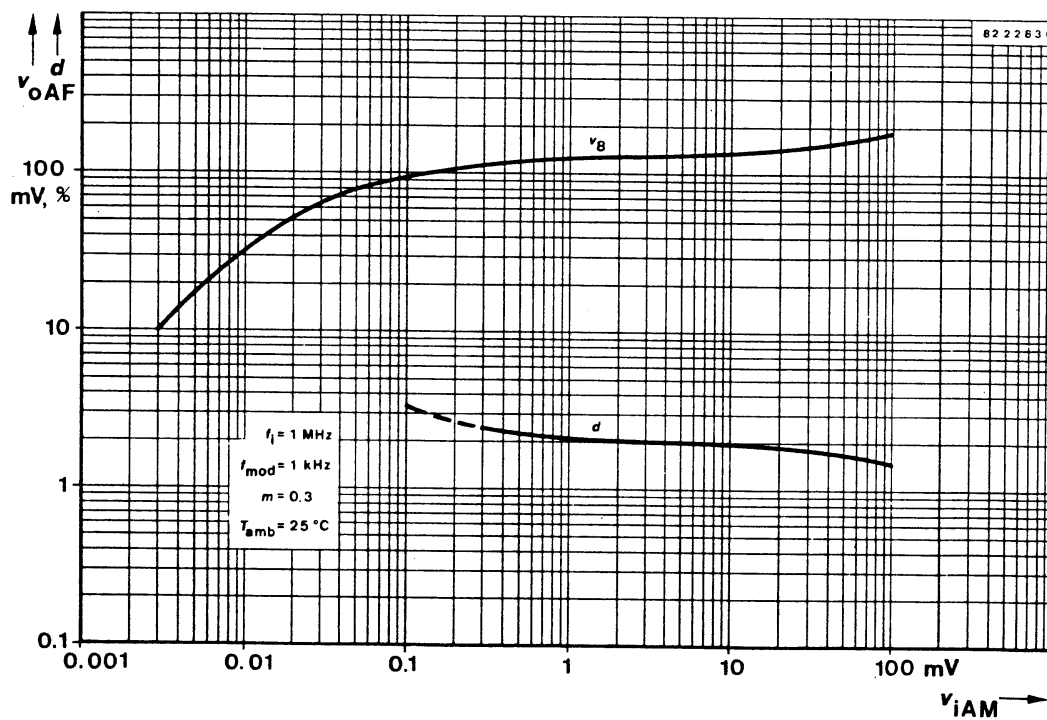


Figure 6.

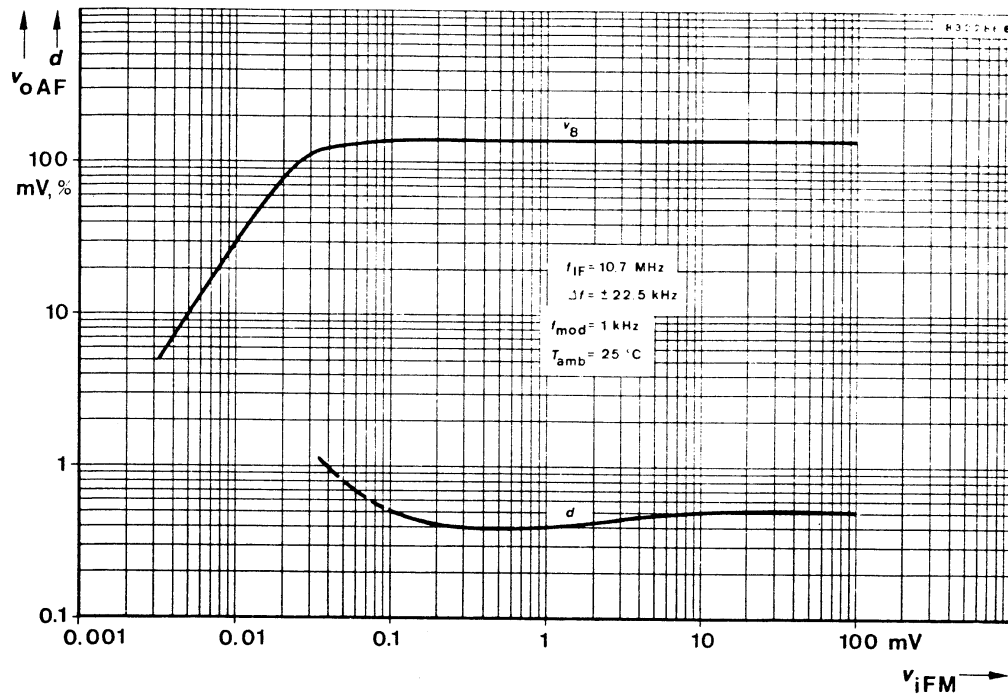


Figure 7.

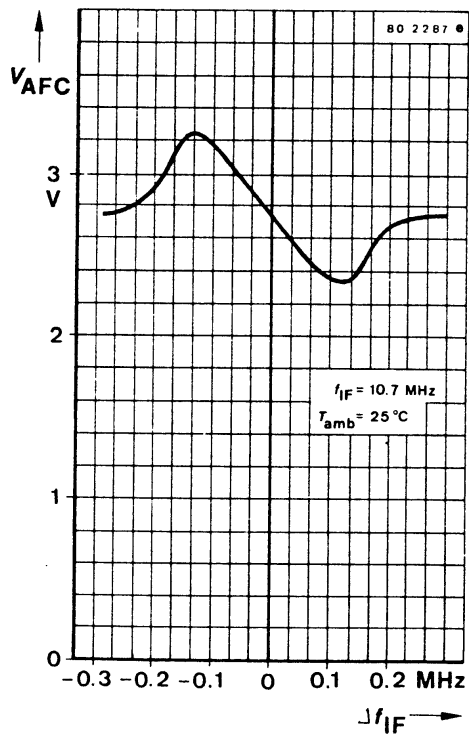


Figure 8.

## Components in Figure 9

L <sub>1</sub>	=	4	Wdg Ø 0.45 CuL, threaded core 7.5x3 material: Fi 01 U8 (Vogt GmbH)
L <sub>2</sub>	=	5	Wdg Ø 0.45 CuL
L <sub>3</sub>	=	5	Wdg Ø 0.45 CuL, air core Ø 3.5 mm
L <sub>4</sub>	=	3+3	Wdg Ø 0.45 CuL, air core Ø 2.7 mm
L <sub>5</sub>	=	12	Wdg Ø 0.25 CuL, Pin 3-1, filter kit 154 AN(C) or 154ANS-7 A6363A0 (TOKO, Componex)
L <sub>6</sub>	=	2	Wdg Ø 0.25 CuL, Pin 4-6
L <sub>7</sub>	=	7	Wdg Ø 0.25 CuL, Pin 6-3, filter kit 154AN(C) or 154EES-7 A6392FA (TOKO, Componex)
L <sub>8</sub>	=	7	Wdg Ø 0.16 CuL, Pin 1-4, filter kit 154AN(C) or 154EES-7 A6391ABM (TOKO, Componex)
L <sub>9</sub>	=	5	Wdg Ø 0.16 CuL, Pin 2-6
L <sub>10</sub>	=	96	Wdg Ø 0.25 CuLs, ferrite aerial Ø 8x130 mm, type 031039-2103-606, (Draloric)
L <sub>11</sub>	=	6	Wdg Ø 0.25 CuLs
L <sub>12</sub>	=	78	Wdg Ø 0.09 CuL, Pin 3-4, filter kit RBR or RWOS-6A7609AAU (TOKO, Componex)
L <sub>13</sub>	=	7	Wdg Ø 0.09 CuL, Pin 2-1
L <sub>14</sub>	=	18	Wdg Ø 0.09 CuL, Pin 3-4, filter kit RHN(C) or RHCS-1A7607AQH (TOKO, Componex)
L <sub>15</sub>	=	46+100	Wdg Ø 0.09 CuL, Pin 6-2-1
L <sub>16</sub>	=	72+72	Wdg Ø 0.09 CuL Pin 3-4/6-1, filter kit RHN(C) or RHNS-1A7608AZP (TOKO, Componex)
455 kHz	=		Ceramic filter LBF 6 (Componex) or CFU 445 H (Stettner)
10.7 MHz	=		Ceramic filter 10.7 MF-18 (Componex) or SFE 10.7 MA (Stettner)
D <sub>r1</sub> , D <sub>r3</sub>	=		Ferrit bead on the transistor terminal
D <sub>r2</sub>	=	16	Wdg Ø 0.25 CuL, Ø 2 air core
D <sub>r4</sub>	=	6	Wdg Ø 0.15 CuL, Ø 2.1x3 mm ferrit bead
C <sub>6</sub> =C <sub>14</sub>	=		4.5 to 20 pF, variable capacitor type CY2-22124-RT02 (TOKO, Componex)
C <sub>19</sub>	=		5 to 80 pF
C <sub>21</sub>	=		5 to 140 pF
R <sub>8</sub>	=		According to gain groups ∞, 47 kΩ or 33 kΩ

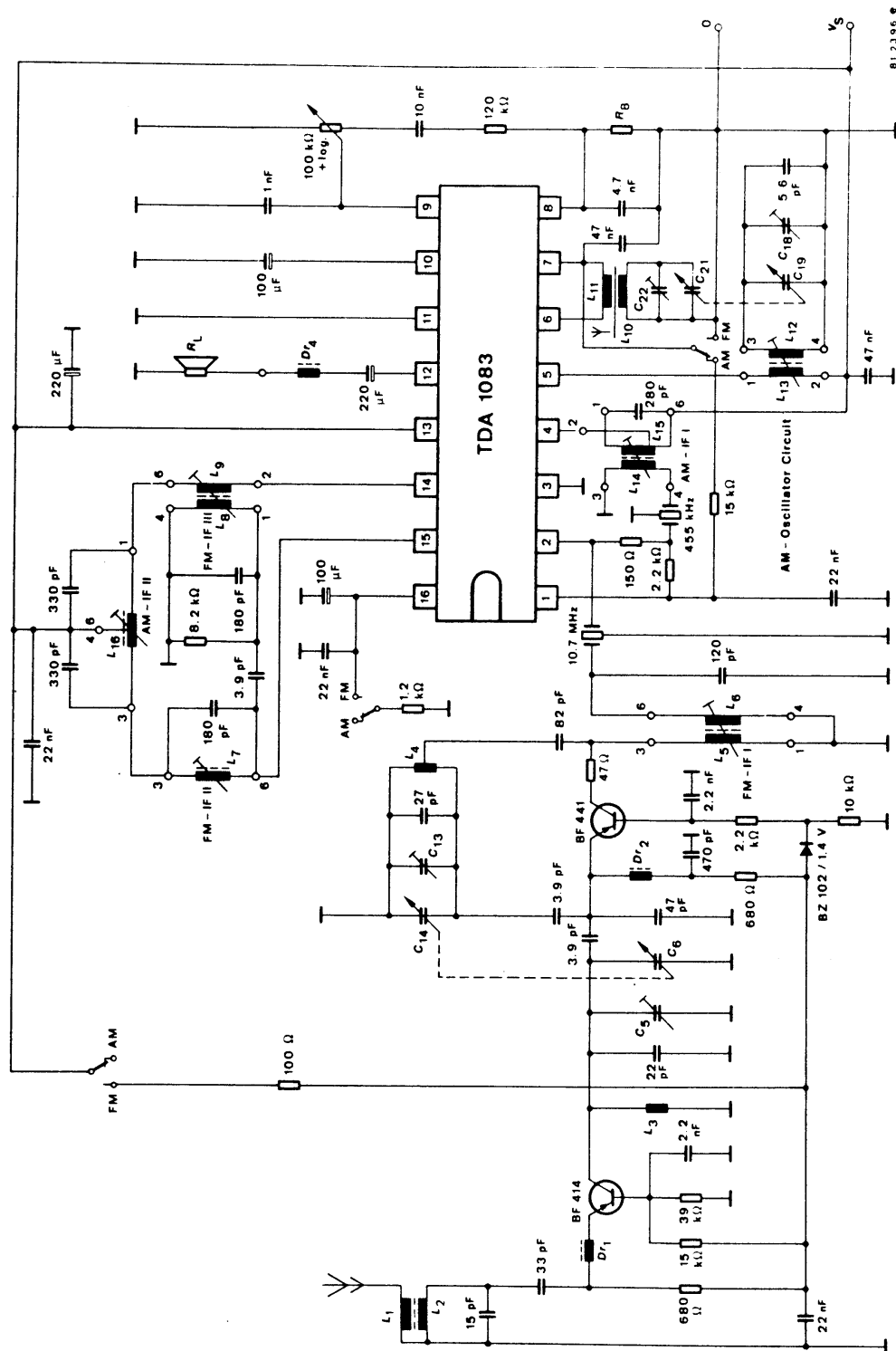


Figure 9. FM-/AM-receiver circuit

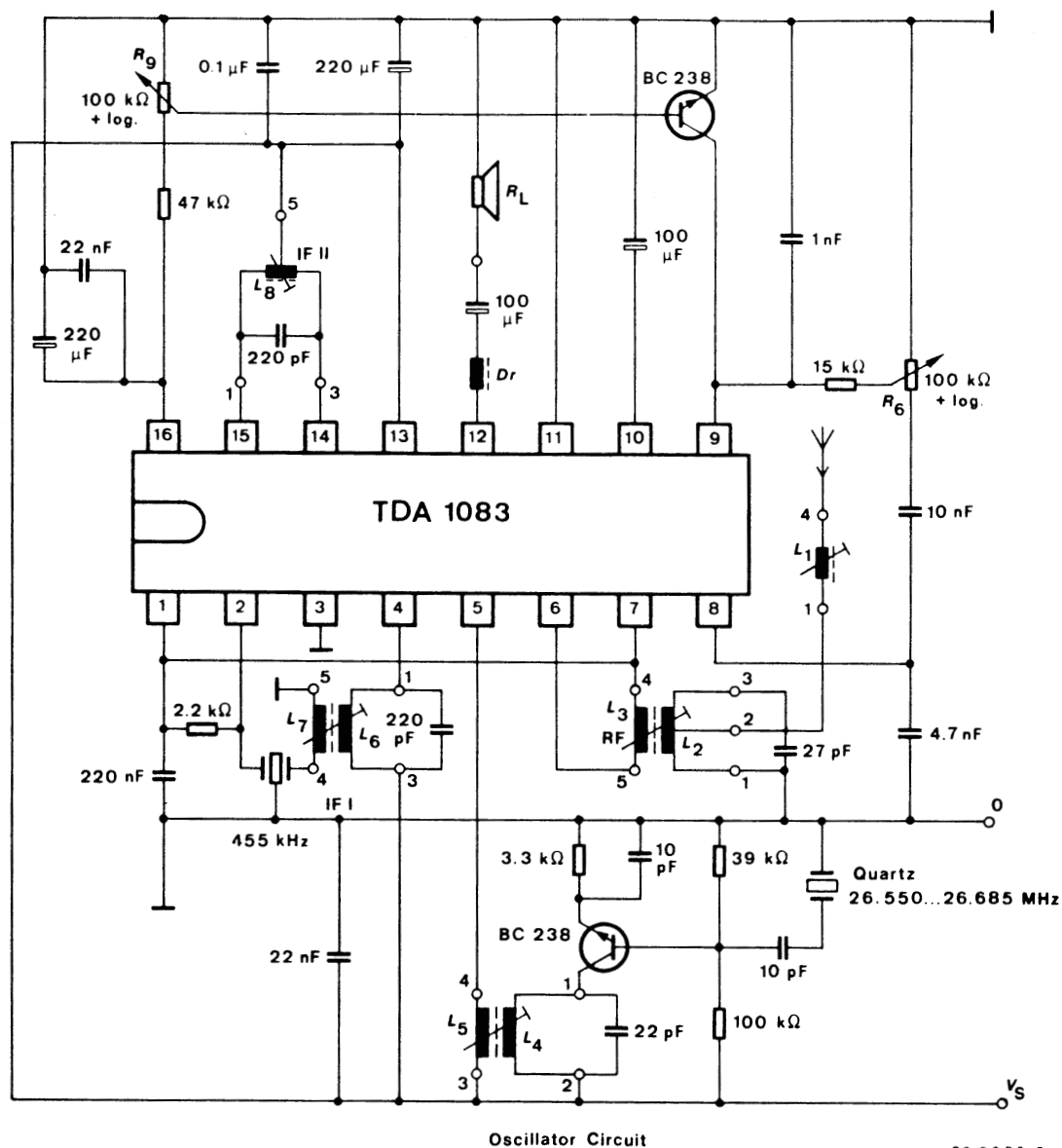
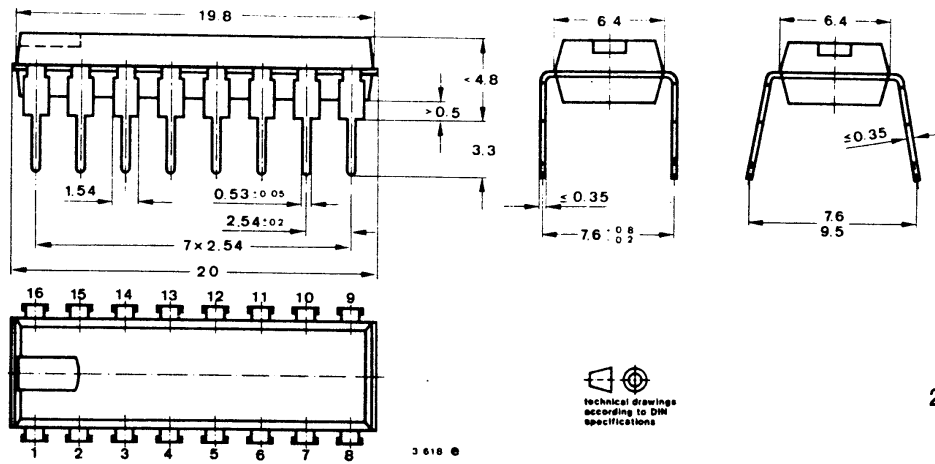


Figure 10.



**Dimensions in mm**



Case  
20 A 16 DIN 41866  
JEDEC MO 001

## Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

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